NSN 5962-01-377-2579

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
End Application:
Flight control e/i fscm 76823
Features Provided:
Bipolar and programmed and tested to mil-std-883
Inclosure Configuration:
Dual-in-line
Case Outline Source And Designator:
D-9 mil-m-38510
Product Name:
Microcircuit digital, pal eeprom read/write generator
Voltage Rating And Type Per Characteristic:
4.5 volts total supply and 5.5 volts total supply
Memory Device Type:
Pal
Hybrid Technology Type:
Monolithic
Special Features:
Nuclear hardness critical items
Nuclear Hardness Critical Feature:
Hardened
Test Data Document:
07690-pg639000-01 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
24 printed circuit
Departure From Cited Designator:
Altered by programming & marking
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
Yes - demil/mli
Fiig:
A458a0